

P-Channel Enhancement-Mode Vertical DMOS FET

Features

- Free from secondary breakdown
- ► Low power drive requirement
- Ease of paralleling
- Low C_{iss} and fast switching speeds
- Excellent thermal stability
- ► Integral source-to-drain diode
- High input impedance and high gain

Applications

- Motor controls
- Converters
- Amplifiers
- Switches
- Power supply circuits
- Drivers (relays, hammers, solenoids, lamps, memories, displays, bipolar transistors, etc.)

General Description

The Supertex VP2110 is an enhancement-mode (normally-off) transistor that utilizes a vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors, and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Ordering Information

	Device	Package Opt	ions	BV _{DSS} /BV _{DGS}	R _{DS(ON)}	I _{D(ON)}	
	Device	TO-236AB (SOT-23)	Die*	(V)	(max) (Ω)	(min) (mA)	
	VP2110	VP2110K1-G	VP2110ND	-100	12	-500	

⁻G indicates package is RoHS compliant ('Green')

^{*} MIL visual screening available





Absolute Maximum Ratings

Parameter	Value
Drain-to-source voltage	BV _{DSS}
Drain-to-gate voltage	BV_{DGS}
Gate-to-source voltage	±20V
Operating and storage temperature	-55°C to +150°C
Soldering temperature*	300°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied. Continuous operation of the device at the absolute rating level may affect device reliability. All voltages are referenced to device ground.

Pin Configuration



TO-236AB (SOT-23) (K1)

Product Marking



W = Code for Week Sealed
____ = "Green" Packaging

Package may or may not include the following marks: Si or \$\mathbb{H}\$

TO-236AB (SOT-23) (K1)

^{*} Distance of 1.6mm from case for 10 seconds.

Thermal Characteristics

Package	I _D (continuous) [†] (mA)	I _D (pulsed) (mA)	Power Dissipation @T _A = 25°C (W)	θ _{jc} (°C/W)	θ _{ja} (°C/W)	† _{DR} † (m A)	I _{DRM} (mA)
TO-236AB (SOT-23)	-120	-400	0.36	200	350	-120	-400

Notes:

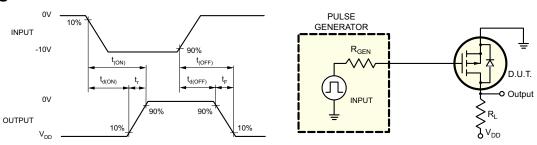
Electrical Characteristics (T_A = 25°C unless otherwise specified)

Sym	Parameter	Min	Тур	Max	Units	Conditions	
BV _{DSS}	Drain-to-Source breakdown voltage	-100	-	-	V	$V_{GS} = 0V, I_{D} = -1.0 \text{mA}$	
$V_{\rm GS(th)}$	Gate threshold voltage	-1.5	-	-3.5	V	$V_{GS} = V_{DS}$, $I_{D} = -1.0$ mA	
$\Delta V_{GS(th)}$	Change in V _{GS(th)} with temperature	-	5.8	6.5	mV/°C	$V_{GS} = V_{DS}$, $I_{D} = -1.0$ mA	
I _{GSS}	Gate body leakage	-	-1.0	-100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
		_	-	-10	μA	$V_{GS} = 0V, V_{DS} = Max Rating$	
I _{DSS}	Zero Gate voltage Drain current	-	-	-1.0	mA	$V_{DS} = 0.8$ Max Rating, $V_{GS} = 0V$, $T_A = 125$ °C	
I _{D(ON)}	On-state Drain current	-0.5	-1.0	-	Α	$V_{GS} = -10V, V_{DS} = -25V$	
D	Static Drain-to-Source on-state resistance		11	15	Ω	$V_{GS} = -5.0V, I_{D} = -100mA$	
R _{DS(ON)}	Static Drain-to-Source on-state resistance	-	9.0	12	22	$V_{GS} = -10V, I_{D} = -500 \text{mA}$	
$\Delta R_{DS(ON)}$	Change in R _{DS(ON)} with temperature	-	0.55	1.0	%/°C	$V_{GS} = -10V, I_{D} = -500mA$	
G _{FS}	Forward transductance	150	200	-	mmho	$V_{DS} = -25V, I_{D} = -500mA$	
C _{ISS}	Input capacitance	-	45	60		V _{GS} = 0V,	
C _{oss}	Common Source output capacitance	-	22	30	pF	$V_{DS} = -25V$,	
C _{RSS}	Reverse transfer capacitance	-	3.0	8.0		f = 1.0MHz	
t _{d(ON)}	Turn-on delay time	-	4.0	5.0)	
t _r	Rise time		5.0	8.0	ns	$V_{DD} = -25V,$ $I_{D} = -500 \text{mA},$	
t _{d(OFF)}			5.0	9.0		$R_{GEN} = 25\Omega$	
t _f	Fall time	-	4.0	8.0		GEN	
V _{SD}	Diode forward voltage drop	-	-1.2	-2.0	V	$V_{GS} = 0V, I_{SD} = -500 \text{mA}$	
t _{rr}	Reverse recovery time	-	400	-	ns	$V_{GS} = 0V, I_{SD} = -500 \text{mA}$	

Notes:

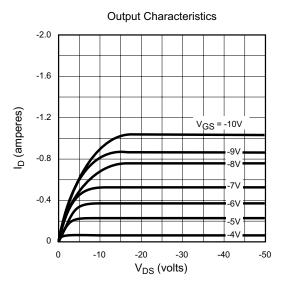
- 1. All D.C. parameters 100% tested at 25°C unless otherwise stated. (Pulse test: 300µs pulse, 2% duty cycle.)
- 2. All A.C. parameters sample tested.

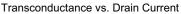
Switching Waveforms and Test Circuit

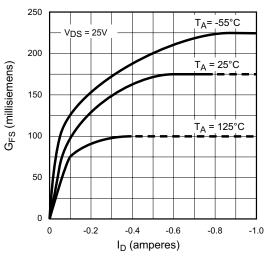


 $[\]dagger$ $I_{\scriptscriptstyle D}$ (continuous) is limited by max rated $T_{\scriptscriptstyle i}$.

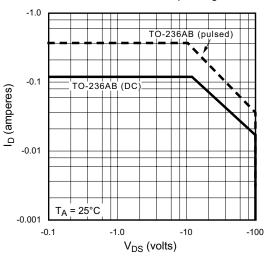
Typical Performance Curves



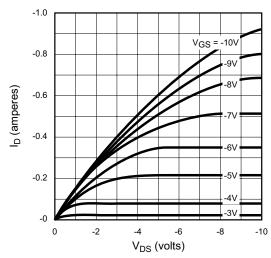




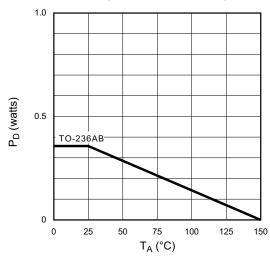
Maximum Rated Safe Operating Area



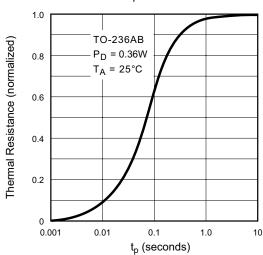
Saturation Characteristics



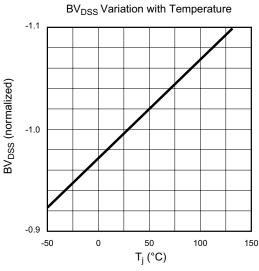
Power Dissipation vs. Ambient Temperature

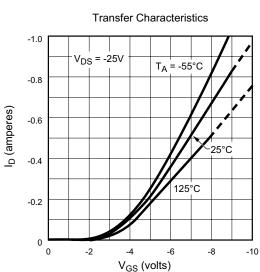


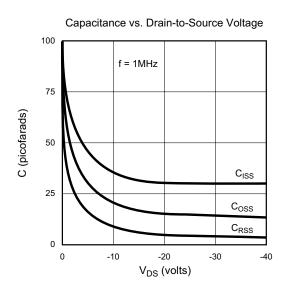
Thermal Response Characteristics

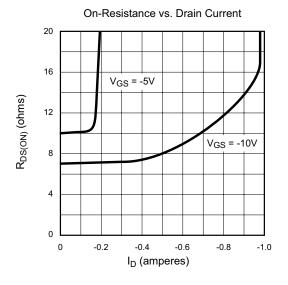


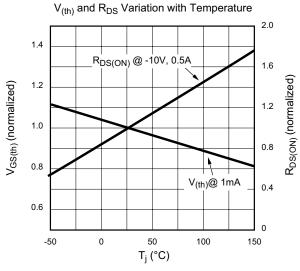
Typical Performance Curves (cont.)

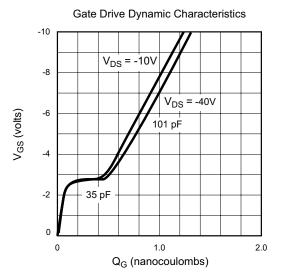






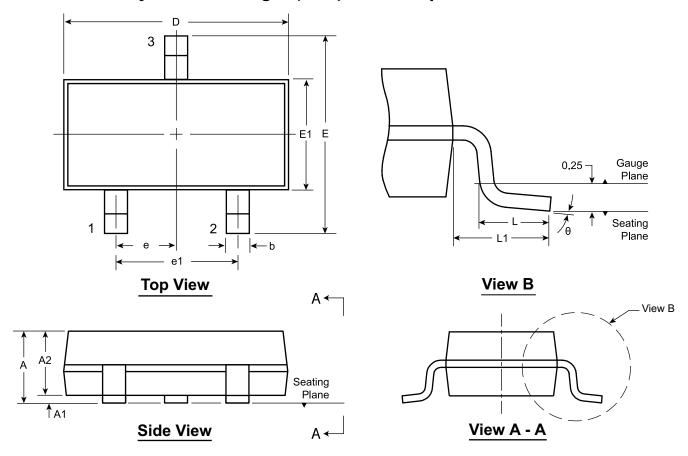






3-Lead TO-236AB (SOT-23) Package Outline (K1/T)

2.90x1.30mm body, 1.12mm height (max), 1.90mm pitch



Symb	ol	Α	A1	A2	b	D	Е	E1	е	e1	L	L1	θ	
	MIN	0.89	0.01	0.88	0.30	2.80	2.10	1.20	0.05	1.90 BSC	1 (15)	0.54 REF	0 °	
Dimension (mm)	NOM	-	-	0.95	-	2.90	-	1.30	0.95 BSC				-	
(11111)	MAX	1.12	0.10	1.02	0.50	3.04	2.64	1.40	ВОО		500	BOC	0.60	1/21

JEDEC Registration TO-236, Variation AB, Issue H, Jan. 1999.

Drawings not to scale.

Supertex Doc.#: DSPD-3TO236ABK1, Version C041309.

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to http://www.supertex.com/packaging.html.)

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[†] This dimension differs from the JEDEC drawing.